

## HIGH VOLTAGE SWITCHING DIODE

- **Applications**

High speed switching

- **Features**

- 1) Small surface mounting type.
- 2) High Speed. ( $t_{rr} = 50\text{ns max.}$ )
- 3) High reliability with high surge current handing capability.

- **Construction**

Silicon epitaxial planar

- **Device Marking and Ordering Information**

Type	BAV21WS
Marking	HT3



### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Continuous Reverse Voltage	$V_R$	250	Vdc
Peak Forward Current	$I_F$	200	mAdc
Peak Forward Surge Current	$I_{FM(surge)}$	625	mAdc

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board,* $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	200	mW
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	635	$^\circ\text{C/W}$
Junction and Storage Temperature Range	$T_J, T_{stg}$	-55 to+150	$^\circ\text{C}$

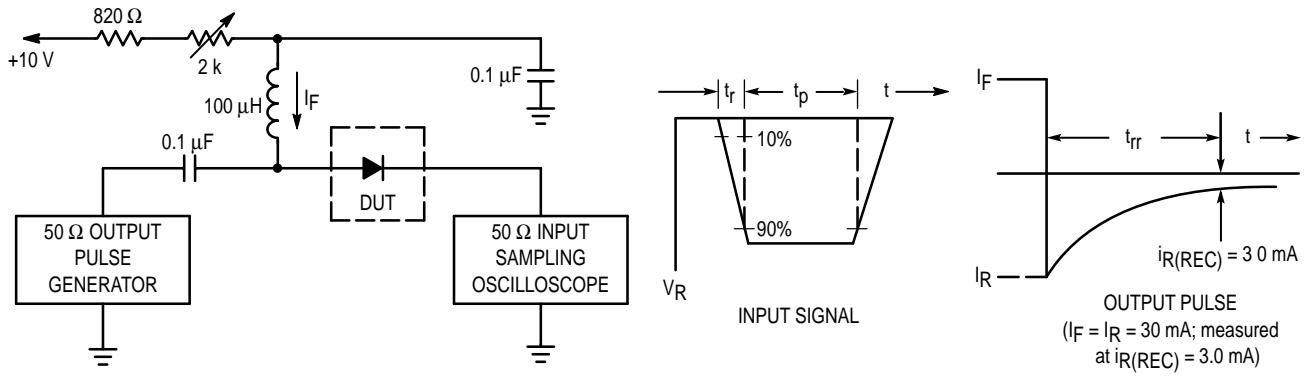
\*FR-5 Minimum Pad

### ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
----------------	--------	-----	-----	------

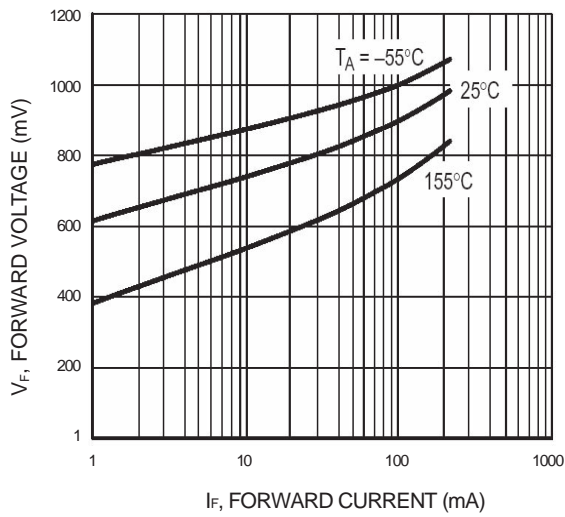
### OFF CHARACTERISTICS

Reverse Voltage Leakage Current ( $V_R = 200\text{ Vdc}$ ) ( $V_R = 200\text{ Vdc}, T_J = 150^\circ\text{C}$ )	$I_R$	-	1.0 100	$\mu\text{Adc}$
Reverse Breakdown Voltage ( $I_{BR} = 100\ \mu\text{Adc}$ )	$V_{(BR)}$	250	-	Vdc
Forward Voltage ( $I_F = 100\text{ mAdc}$ ) ( $I_F = 200\text{ mAdc}$ )	$V_F$	-	1000 1250	mV
Diode Capacitance ( $V_R = 0, f = 1.0\text{ MHz}$ )	$C_D$	-	5.0	pF
Reverse Recovery Time ( $I_F = I_R = 30\text{ mAdc}, R_L = 100\ \Omega$ )	$t_{rr}$	-	50	ns

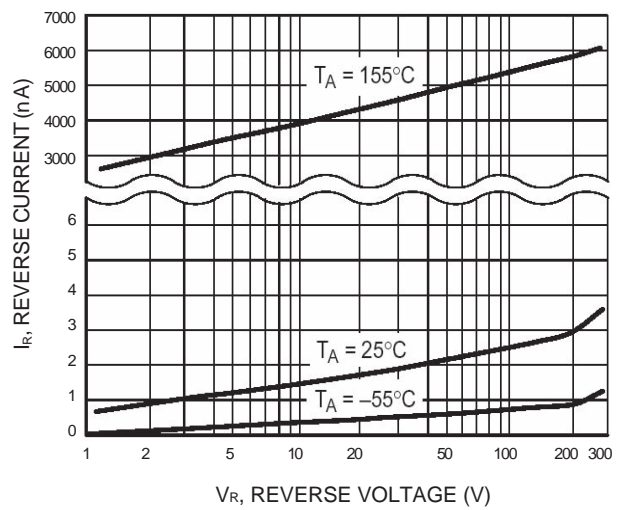


- Notes: 1. A 2.0 kΩ variable resistor adjusted for a Forward Current ( $I_F$ ) of 30 mA.  
 2. Input pulse is adjusted so  $I_{R(\text{peak})}$  is equal to 30 mA.  
 3.  $t_p \gg t_{rr}$

**Figure 1. Recovery Time Equivalent Test Circuit**

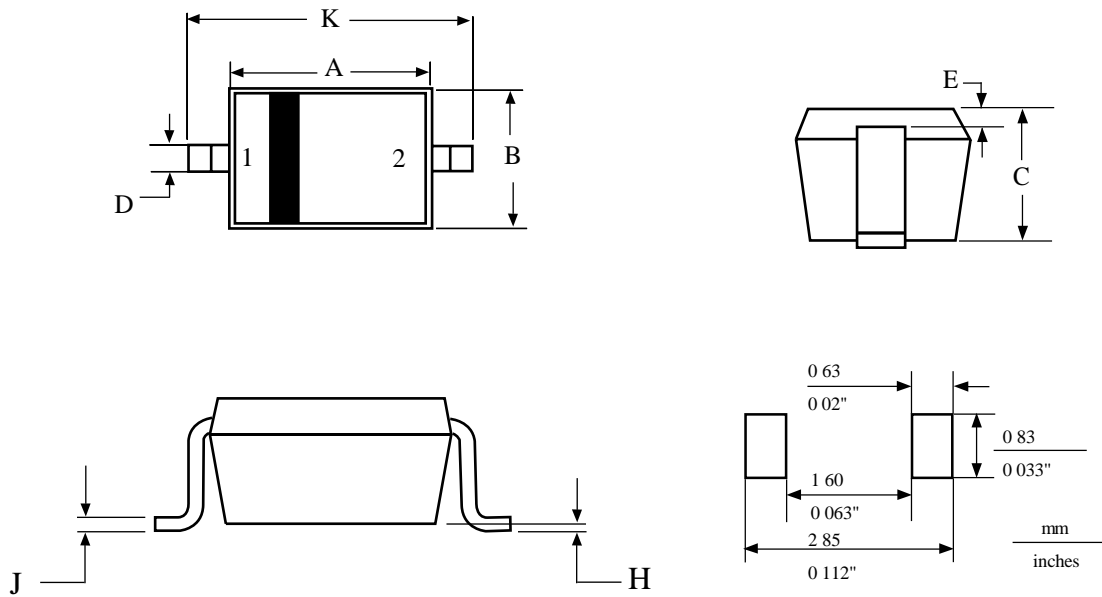


**Figure 2. Forward Voltage**



**Figure 3. Reverse Leakage**

## SC-76 / SOD-323



**NOTES:**

1. DIMENSIONING AND TOLERANCING  
PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETERS

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.60	1.80	0.063	0.071
b	1.15	1.35	0.045	0.053
C	0.80	1.00	0.031	0.039
D	0.25	0.40	0.010	0.016
E	0.15 REF		0.006 REF	
H	0.00	0.10	0.000	0.004
J	0.089	0.177	0.0035	0.0070
K	2.30	2.70	0.091	0.106

PIN:1:CATHODE  
2:ANODE